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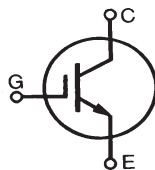
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



# 1200V XPT™ GenX3™ IGBTs

## IXYA20N120C3HV IXYP20N120C3 IXYH20N120C3

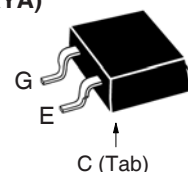
High-Speed IGBT  
for 20-50 kHz Switching



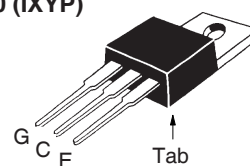
$V_{CES} = 1200V$   
 $I_{C110} = 20A$   
 $V_{CE(sat)} \leq 3.4V$   
 $t_{fi(typ)} = 108ns$

| Symbol                        | Test Conditions  | Maximum Ratings                          |            |
|-------------------------------|--|--|------------|
| $V_{CES}$                     | $T_J = 25^\circ C$ to $175^\circ C$  | 1200                                     | V          |
| $V_{CGR}$                     | $T_J = 25^\circ C$ to $175^\circ C$ , $R_{GE} = 1M\Omega$                            | 1200                                     | V          |
| $V_{GES}$                     | Continuous   | $\pm 20$                                 | V          |
| $V_{GEM}$                     | Transient  | $\pm 30$                                 | V          |
| $I_{C25}$                     | $T_C = 25^\circ C$   | 40                                       | A          |
| $I_{C110}$                    | $T_C = 110^\circ C$  | 20                                       | A          |
| $I_{CM}$                      | $T_C = 25^\circ C$ , 1ms   | 96                                       | A          |
| $I_A$                         | $T_C = 25^\circ C$   | 10                                       | A          |
| $E_{AS}$                      | $T_C = 25^\circ C$   | 400                                      | mJ         |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15V$ , $T_{VJ} = 150^\circ C$ , $R_G = 10\Omega$<br>Clamped Inductive Load | $I_{CM} = 40$<br>@ $V_{CE} \leq V_{CES}$ | A          |
| $P_C$                         | $T_C = 25^\circ C$   | 278                                      | W          |
| $T_J$                         |  | -55 ... +175                             | $^\circ C$ |
| $T_{JM}$                      |  | 175                                      | $^\circ C$ |
| $T_{stg}$                     |  | -55 ... +175                             | $^\circ C$ |
| $T_L$                         | Maximum Lead Temperature for Soldering   | 300                                      | $^\circ C$ |
| $T_{SOLD}$                    | 1.6 mm (0.062in.) from Case for 10s  | 260                                      | $^\circ C$ |
| $M_d$                         | Mounting Torque (TO-220 & TO247)   | 1.13/10                                  | Nm/lb.in.  |
| $F_c$                         | Mounting Force (TO-263)  | 10..65 / 22..14.6                        | N/lb       |
| <b>Weight</b>                 | TO-263   | 2.5                                      | g          |
|                               | TO-220   | 3.0                                      | g          |
|                               | TO-247   | 6.0                                      | g          |

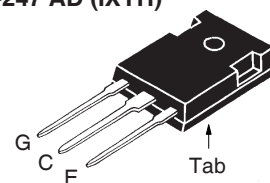
TO-263HV (IXYA)



TO-220 (IXYP)



TO-247 AD (IXYH)



G = Gate                      C = Collector  
 E = Emitter                Tab = Collector

### Features

- High Voltage Package
- Optimized for Low Switching Losses
- Square RBSOA
- Positive Thermal Coefficient of  $V_{ce(sat)}$
- Avalanche Rated
- International Standard Packages

### Advantages

- High Power Density
- Low Gate Drive Requirement

### Applications

- High Frequency Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

| Symbol        | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified) | Characteristic Values |      |                           |
|---------------|---|-----------------------|------|---------------------------|
|               |   | Min.                  | Typ. | Max.                      |
| $BV_{CES}$    | $I_C = 250\mu A$ , $V_{GE} = 0V$                                      | 1200                  |      | V                         |
| $V_{GE(th)}$  | $I_C = 250\mu A$ , $V_{CE} = V_{GE}$                                  | 3.0                   |      | 5.0 V                     |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0V$<br>$T_J = 150^\circ C$             |                       |      | 15 $\mu A$<br>500 $\mu A$ |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$                                    |                       |      | $\pm 100$ nA              |
| $V_{CE(sat)}$ | $I_C = 20A$ , $V_{GE} = 15V$ , Note 1<br>$T_J = 150^\circ C$          |                       | 4.0  | 3.4 V<br>V                |

**Symbol Test Conditions**

( $T_J = 25^\circ\text{C}$  Unless Otherwise Specified)

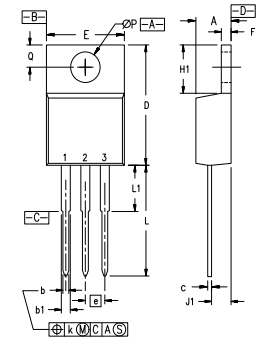
**Characteristic Values**

|              |  | Min. | Typ. | Max. |                    |
|--------------|--|------|------|------|--------------------|
| $g_{fs}$     | $I_C = 20\text{A}, V_{CE} = 10\text{V}, \text{Note 1}$   | 7.0  | 11.5 |      | S                  |
| $C_{ies}$    | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$   |      | 1110 |      | pF                 |
| $C_{oes}$    |  |      | 70   |      | pF                 |
| $C_{res}$    |  |      | 27   |      | pF                 |
| $Q_{g(on)}$  | $I_C = 20\text{A}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$  |      | 53   |      | nC                 |
| $Q_{ge}$     |  |      | 9    |      | nC                 |
| $Q_{gc}$     |  |      | 22   |      | nC                 |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 20\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 10\Omega$<br>Note 2  |      | 20   |      | ns                 |
| $t_{ri}$     |  |      | 29   |      | ns                 |
| $E_{on}$     |  |      | 1.3  |      | mJ                 |
| $t_{d(off)}$ |  |      | 90   |      | ns                 |
| $t_{fi}$     |  |      | 108  |      | ns                 |
| $E_{off}$    |  | 0.5  | 1.0  |      | mJ                 |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 150^\circ\text{C}</math></b><br>$I_C = 20\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 10\Omega$<br>Note 2 |      | 20   |      | ns                 |
| $t_{ri}$     |  |      | 40   |      | ns                 |
| $E_{on}$     |  |      | 3.7  |      | mJ                 |
| $t_{d(off)}$ |  |      | 115  |      | ns                 |
| $t_{fi}$     |  |      | 105  |      | ns                 |
| $E_{off}$    |  | 0.7  |      | mJ   |                    |
| $R_{thJC}$   |  |      |      | 0.54 | $^\circ\text{C/W}$ |
| $R_{thCS}$   | TO-220   |      | 0.50 |      | $^\circ\text{C/W}$ |
| $R_{thCS}$   | TO-247   |      | 0.21 |      | $^\circ\text{C/W}$ |

**Notes:**

1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. Switching times & energy losses may increase for higher  $V_{CE}(\text{clamp})$ ,  $T_J$  or  $R_G$ .

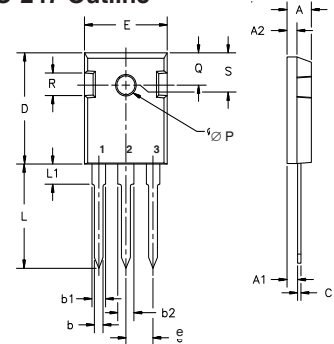
**TO-220 Outline**



Pins: 1 - Gate 2 - Collector  
3 - Emitter

| SYM             | INCHES   |      | MILLIMETERS |       |
|-----------------|----------|------|-------------|-------|
|                 | MIN      | MAX  | MIN         | MAX   |
| A               | .170     | .190 | 4.32        | 4.83  |
| b               | .025     | .040 | 0.64        | 1.02  |
| b1              | .045     | .065 | 1.15        | 1.65  |
| c               | .014     | .022 | 0.35        | 0.56  |
| D               | .580     | .630 | 14.73       | 16.00 |
| E               | .390     | .420 | 9.91        | 10.66 |
| e               | .100 BSC |      | 2.54 BSC    |       |
| F               | .045     | .055 | 1.14        | 1.40  |
| H1              | .230     | .270 | 5.85        | 6.85  |
| J1              | .090     | .110 | 2.29        | 2.79  |
| k               | 0        | .015 | 0           | 0.38  |
| L               | .500     | .550 | 12.70       | 13.97 |
| L1              | .110     | .230 | 2.79        | 5.84  |
| $\varnothing P$ | .139     | .161 | 3.53        | 4.08  |
| Q               | .100     | .125 | 2.54        | 3.18  |

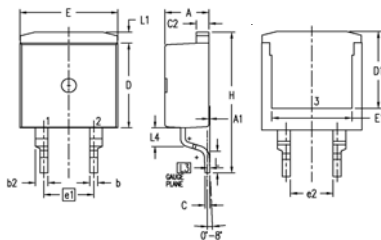
**TO-247 Outline**



Terminals: 1 - Gate 2 - Collector  
3 - Emitter

| Dim.            | Millimeter |       | Inches |       |
|-----------------|------------|-------|--------|-------|
|                 | Min.       | Max.  | Min.   | Max.  |
| A               | 4.7        | 5.3   | .185   | .209  |
| A <sub>1</sub>  | 2.2        | 2.54  | .087   | .102  |
| A <sub>2</sub>  | 2.2        | 2.6   | .059   | .098  |
| b               | 1.0        | 1.4   | .040   | .055  |
| b <sub>1</sub>  | 1.65       | 2.13  | .065   | .084  |
| b <sub>2</sub>  | 2.87       | 3.12  | .113   | .123  |
| C               | .4         | .8    | .016   | .031  |
| D               | 20.80      | 21.46 | .819   | .845  |
| E               | 15.75      | 16.26 | .610   | .640  |
| e               | 5.20       | 5.72  | 0.205  | 0.225 |
| L               | 19.81      | 20.32 | .780   | .800  |
| L1              |            | 4.50  |        | .177  |
| $\varnothing P$ | 3.55       | 3.65  | .140   | .144  |
| Q               | 5.89       | 6.40  | 0.232  | 0.252 |
| R               | 4.32       | 5.49  | .170   | .216  |
| S               | 6.15       | BSC   | 242    | BSC   |

**TO-263HV Outline**



PIN: 1 - Gate  
2 - Emitter  
3 - Collector

| SYM  | INCHES   |      | MILLIMETER |       |
|------|----------|------|------------|-------|
|      | MIN      | MAX  | MIN        | MAX   |
| A    | .170     | .185 | 4.30       | 4.70  |
| A1   | .000     | .008 | 0.00       | 0.20  |
| A2   | .091     | .098 | 2.30       | 2.50  |
| b    | .028     | .035 | 0.70       | 0.90  |
| b2   | .046     | .054 | 1.18       | 1.38  |
| C    | .018     | .024 | 0.45       | 0.60  |
| C2   | .049     | .055 | 1.25       | 1.40  |
| D    | .354     | .370 | 9.00       | 9.40  |
| D1   | .311     | .327 | 7.90       | 8.30  |
| E    | .386     | .402 | 9.80       | 10.20 |
| E1   | .307     | .323 | 7.80       | 8.20  |
| e1   | .200 BSC |      | 5.08 BSC   |       |
| (e2) | .163     | .174 | 4.13       | 4.43  |
| H    | .591     | .614 | 15.00      | 15.60 |
| L    | .079     | .102 | 2.00       | 2.60  |
| L1   | .039     | .055 | 1.00       | 1.40  |
| L3   | .010 BSC |      | 0.254 BSC  |       |
| (L4) | .071     | .087 | 1.80       | 2.20  |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|  |           |           |           |           |              |              |              |              |              |             |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|  | 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$

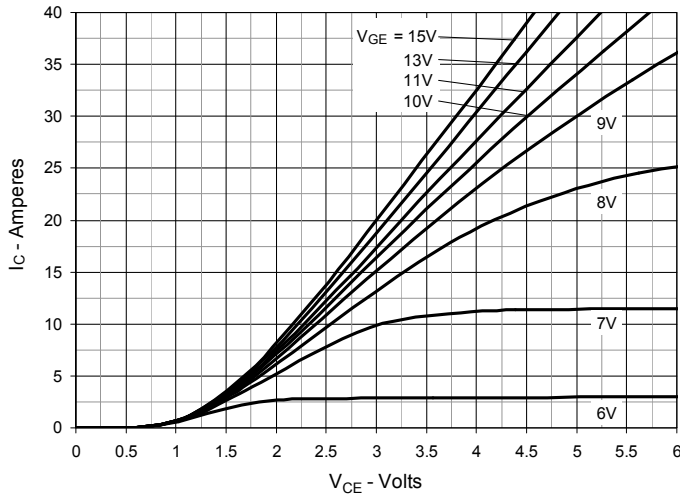


Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$

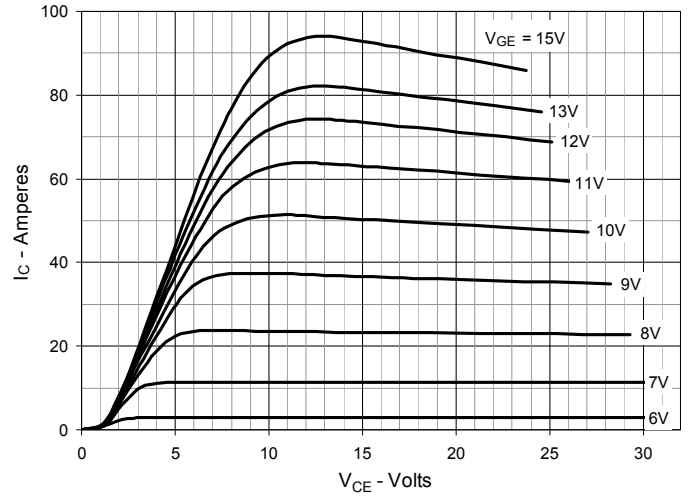


Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$

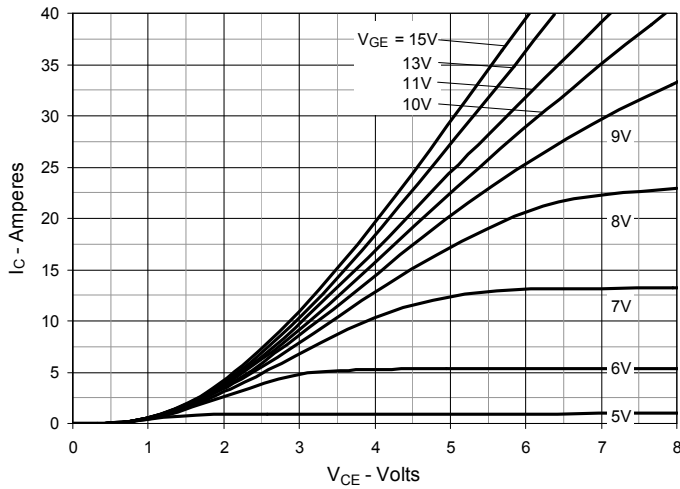


Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature

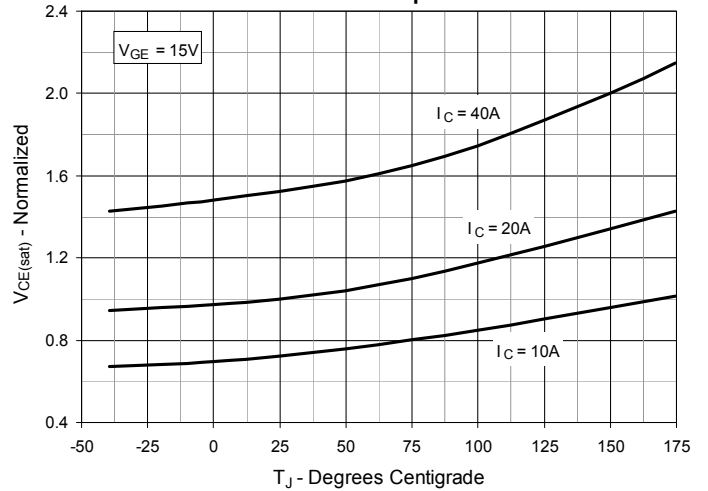


Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage

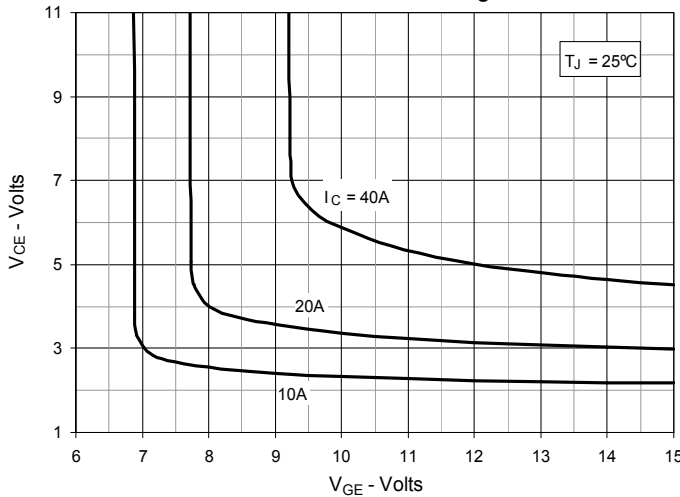
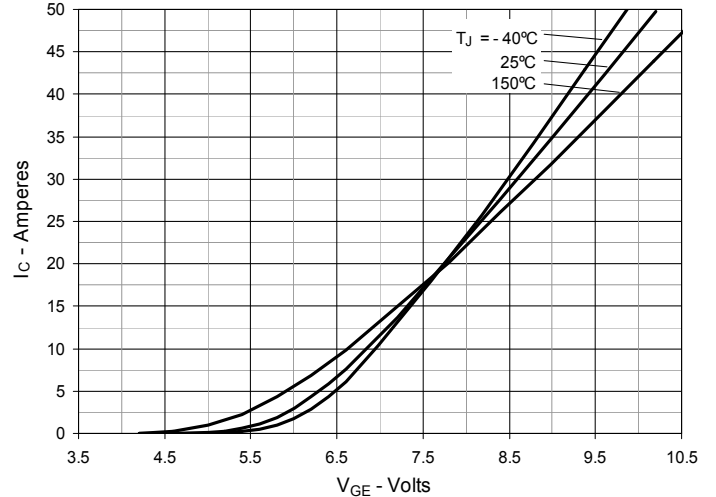
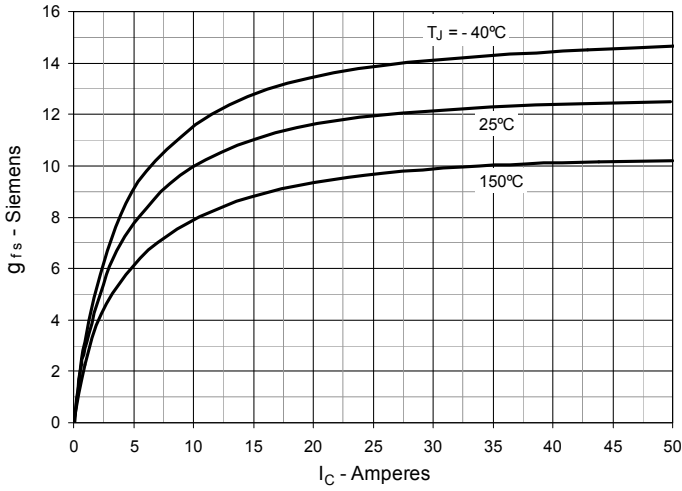


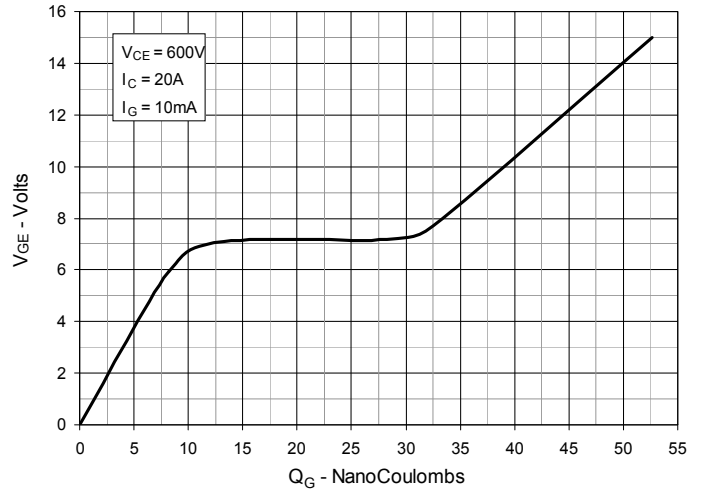
Fig. 6. Input Admittance



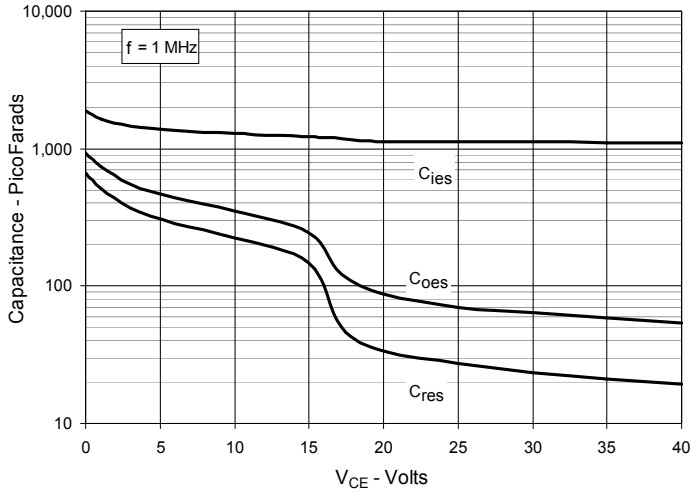
**Fig. 7. Transconductance**



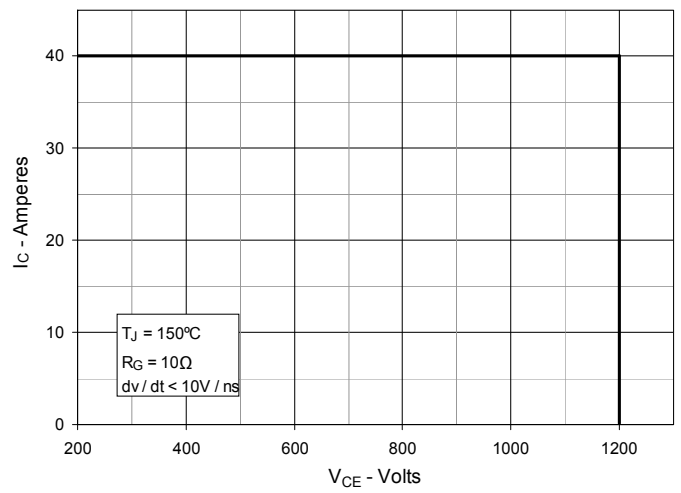
**Fig. 8. Gate Charge**



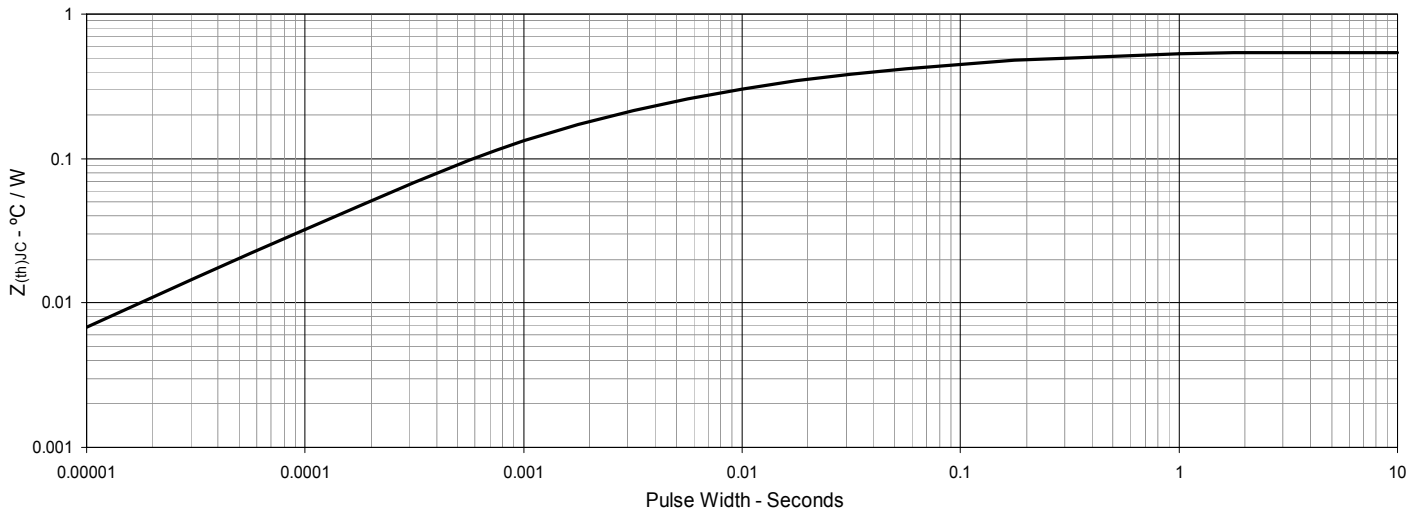
**Fig. 9. Capacitance**



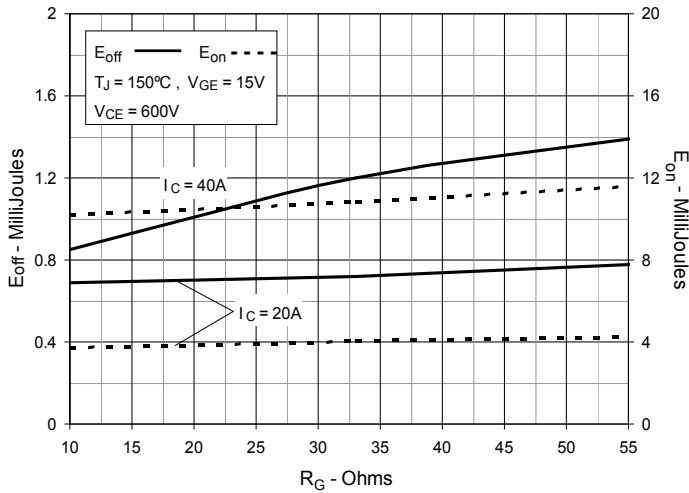
**Fig. 10. Reverse-Bias Safe Operating Area**



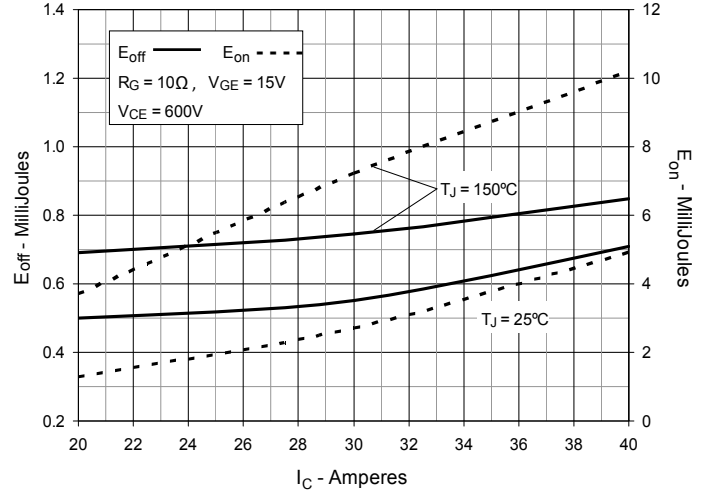
**Fig. 11. Maximum Transient Thermal Impedance**



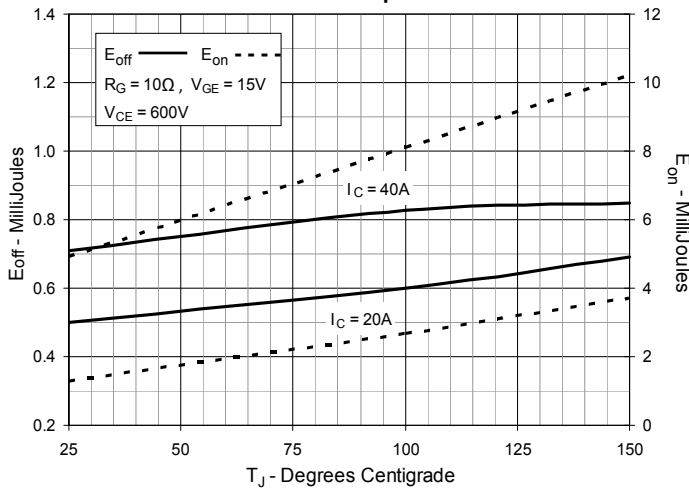
**Fig. 12. Inductive Switching Energy Loss vs. Gate Resistance**



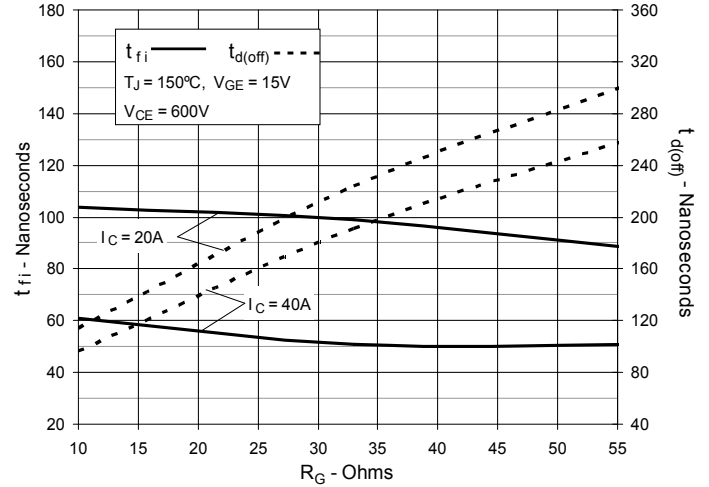
**Fig. 13. Inductive Switching Energy Loss vs. Collector Current**



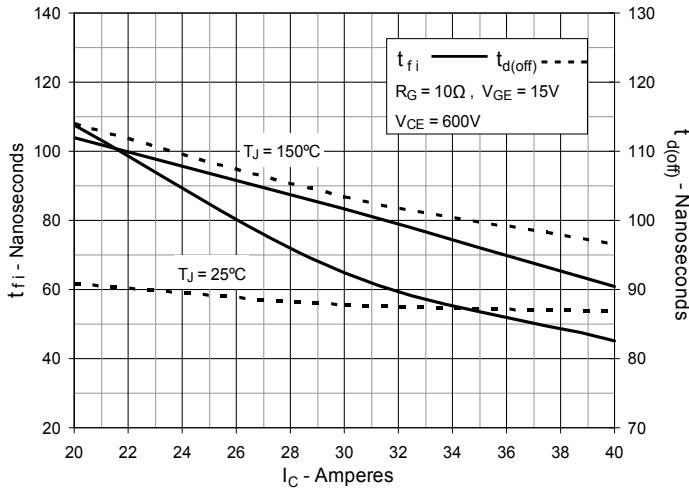
**Fig. 14. Inductive Switching Energy Loss vs. Junction Temperature**



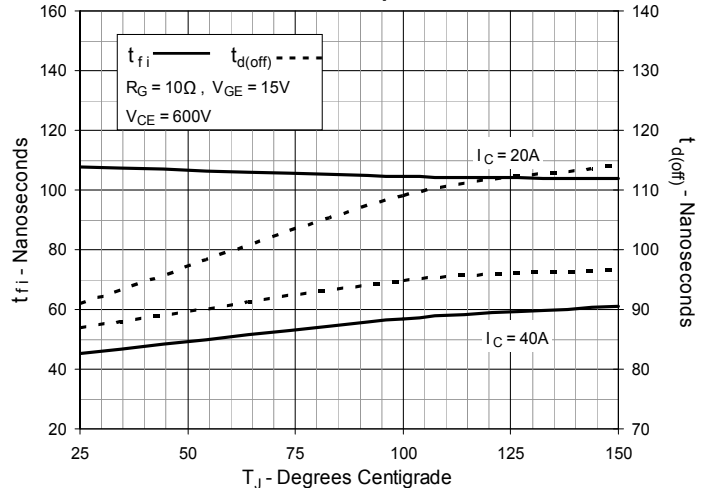
**Fig. 15. Inductive Turn-off Switching Times vs. Gate Resistance**



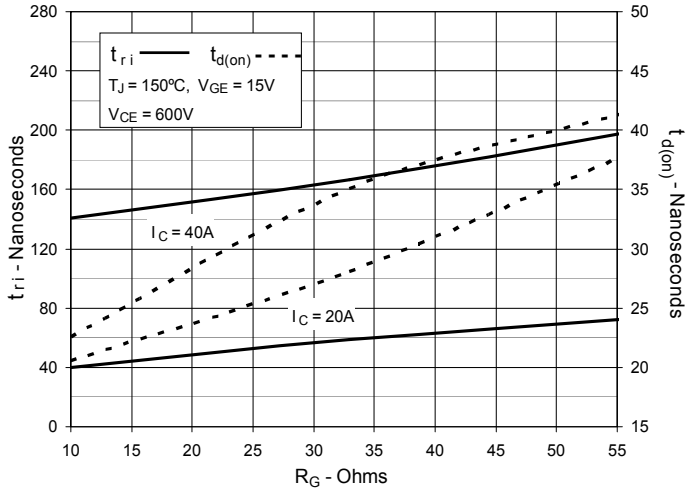
**Fig. 16. Inductive Turn-off Switching Times vs. Collector Current**



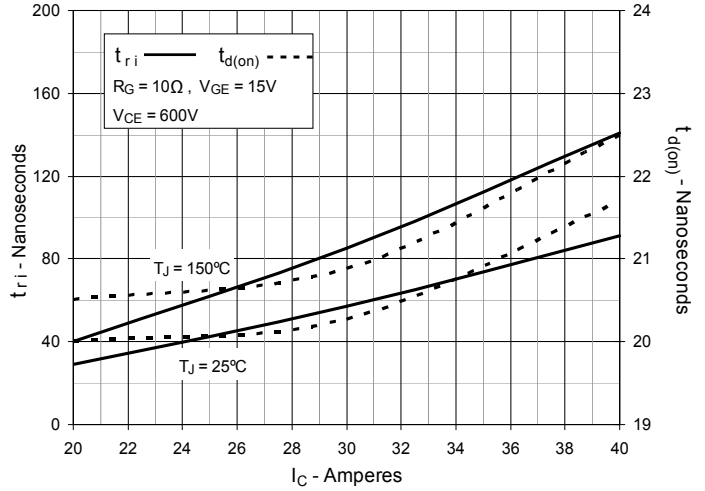
**Fig. 17. Inductive Turn-off Switching Times vs. Junction Temperature**



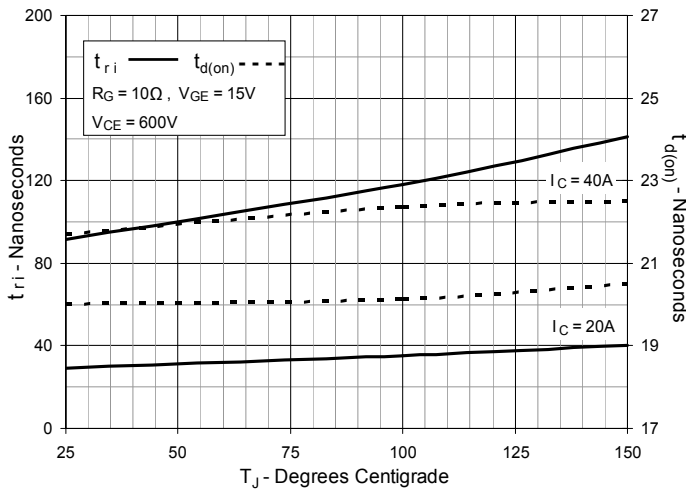
**Fig. 18. Inductive Turn-on Switching Times vs. Gate Resistance**



**Fig. 19. Inductive Turn-on Switching Times vs. Collector Current**



**Fig. 20. Inductive Turn-on Switching Times vs. Junction Temperature**



**Fig. 21. Maximum Peak Load Current vs. Frequency**

